

Replacement Sheet

Attorney Docket No. 24061.148

UTILIZE DEEP TRENCH STRUCTURE TO PREVENT LDMOS FROM PARASITIC TURNING-ON CHANNELS

SHEET 1 OF 3

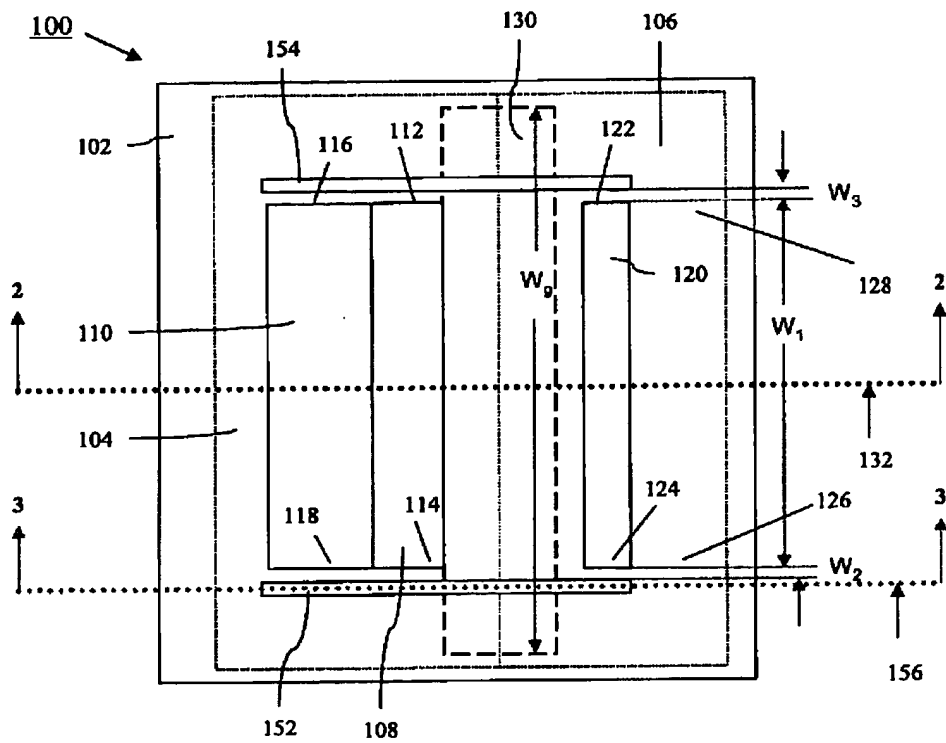


Fig. 1

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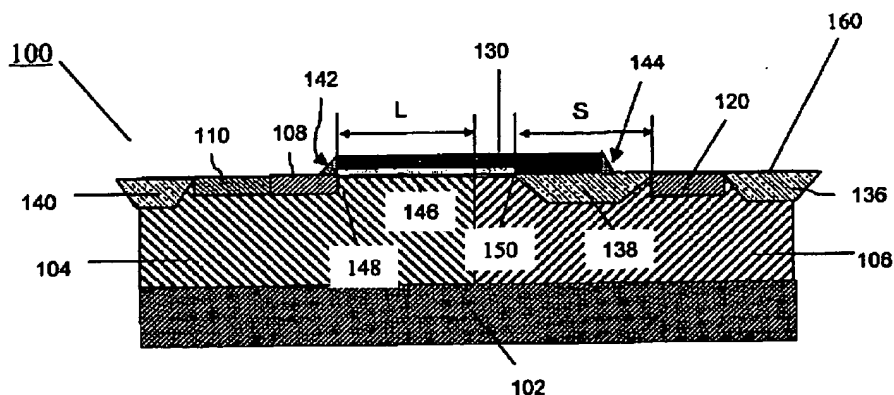


Fig. 2

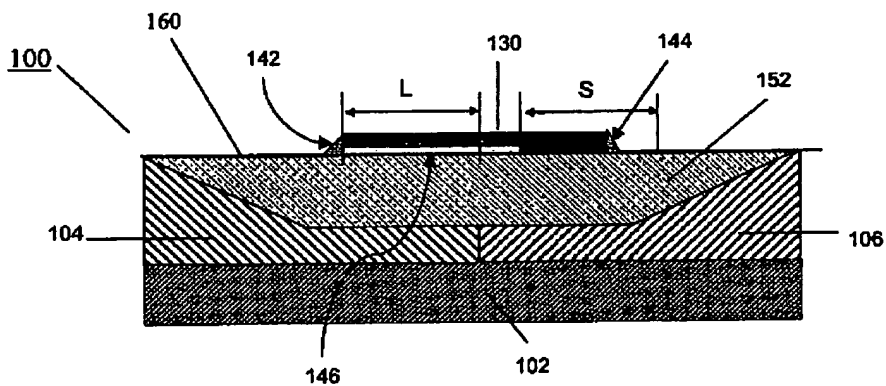


Fig. 3

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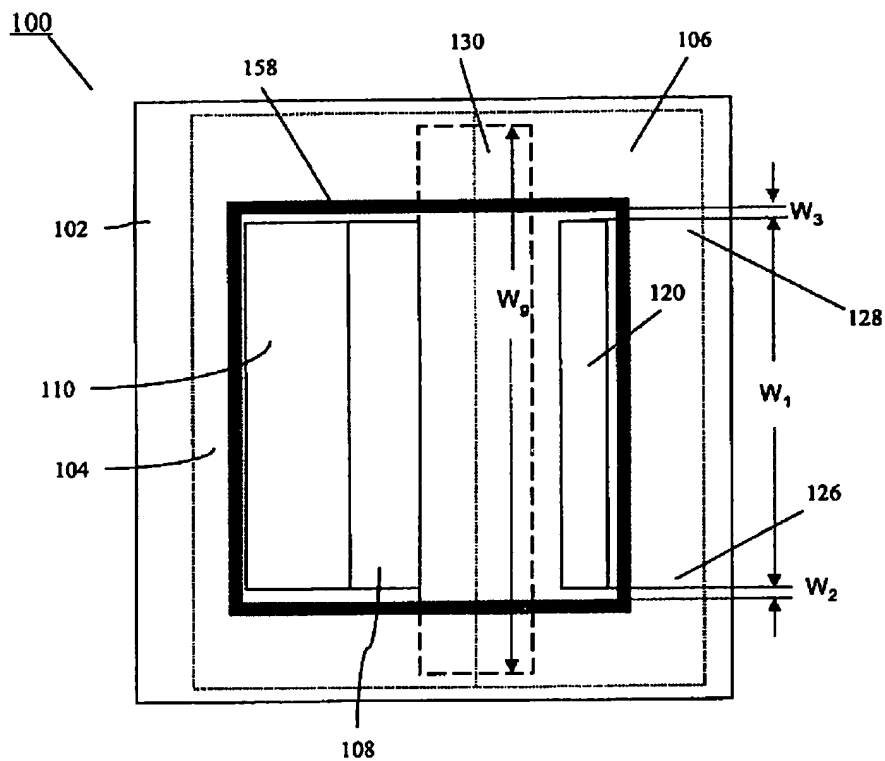


Fig. 4